## MODELLING SPACE-CHARGE-LIMITED CURRENT (SCLC) IN SEMICONDUCTORS

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Vacuum Tube

Repulsion due to

electron cloud

negatively charged



POSTER 3 & 4

## BACKGROUND INFORMATION



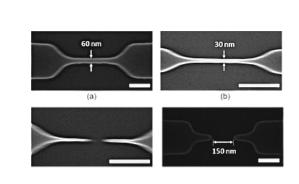
#### <u>Vacuum Tubes - 1950s</u>

- Used in first-generation computers, radios,
- Cons: Large in size, fragile, high energy usage
- transmitters



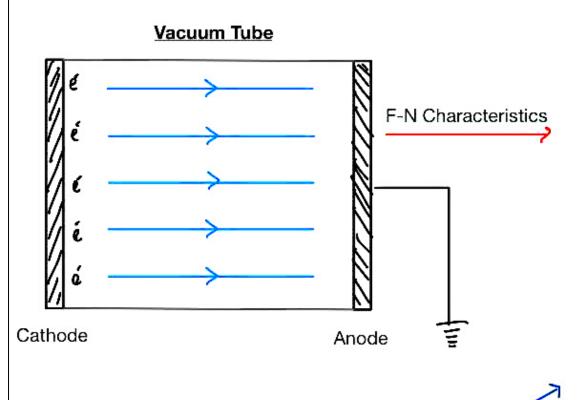
#### Solid State Transistors

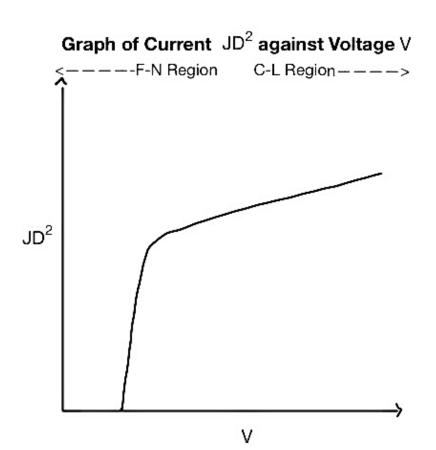
- Semiconductor device
- Pros: Much smaller, reduced energy usage
- Cons: Vulnerable to EMP blat (strong E field) fry semiconductor chip



#### Modern Vacuum nano-electronics

- Remains relevant in key electronic systems:
  - Radar Systems, Electronic Warfare, Spacecraft, Microwave communication systems



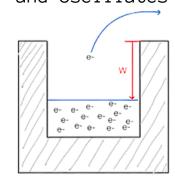


## Types of Electron Emission

• Liberation of electrons from the surface that is stimulated by radiation (lasers), temperature (heating element), strong electric field (quantum tunnelling)

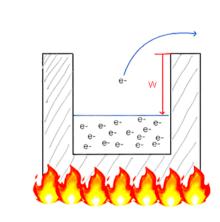
#### Photoelectric Effect

• Emission due to EM Waves **hf>W**: electron escapes well hf⟨W: electron can't escape and oscillates



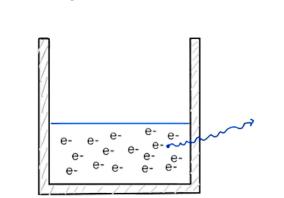
### Thermionic Emission

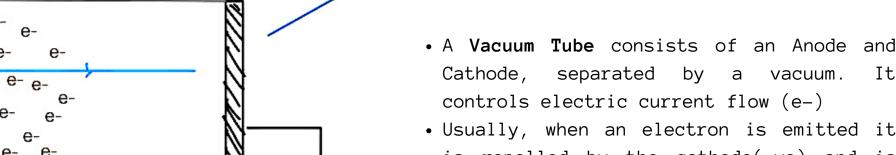
• Emission due to thermal eg. from a resistor



### Field Emission

• Reduces the barrier of the well which allows for quantum tunnelling





- is repelled by the cathode(-ve) and is accelerated by the anode (+ve) • However, at high voltages, the emitted
- electrons saturate the vacuum space which repels low-energy electrons
- This results in a Space Charge Limited Current

## PROBLEM STATEMENT

How does current conduction transit from field emission to space charge limited in semiconductors?

## **03** MODELLING SCLC WITHOUT COLLISION

Using the Fowler-Nordheim Poisson's Equation and conservation of energy, the equation for the velocity and displacement of an electron (vacuum field emission) can be derived

## <u>Vacuum</u>

 $eV = \frac{1}{2}mv^2$ 

Conservation of energy:

Poisson equation:

Poisson equation (Llewllyn form):

Traditional Fowler-

Nordheim Law:

 $\frac{d^2V}{dx^2} = \frac{en}{\varepsilon_0}$ 

 $J = AE_S^2 e^{-\frac{B}{E_S}}$ 

$$\xi^{2} e^{-\frac{B}{E_{S}}}$$
  $\xi^{2}(\xi+3) = 6\bar{D}\bar{E}(e^{-2/\bar{E}})$ 

$$ar{T} = rac{\xi}{\overline{F}} e^{1/\overline{E}}$$

As the direct J-V

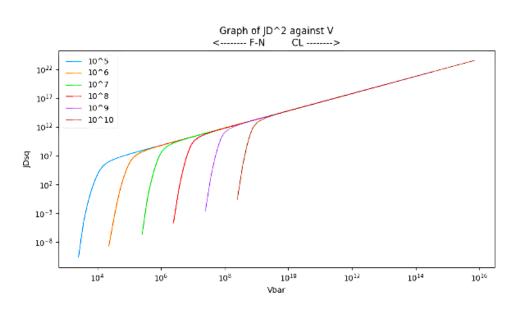
relationship is difficult

to derive analytically, E

is used as an intermediary

relationship numerically

variable to determine their



Graph generated in python

Anode x = D

C-L Characteristics

 $\bar{J}\,\bar{D}^2$ 

Fowler-Nordheim

Child-Langmuir

Dbar: 0.01

Dbar: 0.1

Dbar: 1

 $10^{3}$ 

Dbar: 10

Dbar: 100

 $10^{4}$ 

Graph in 1994 paper

 $x(t) = \frac{eJ}{6m\epsilon_0}t^3 + \frac{eE_S}{2m}t^2$  $v(t) = \frac{eJ}{2m\epsilon_0}t^2 + \frac{e}{m}E_S t$ 

# $\xi = -1 + \sqrt{1 + 2(2\bar{V})^{0.5}e^{-1/\bar{E}}}$

Cathode

x=0

Using these equations, a J-V graph was generated to verify the transition from Fowler-Nordheim Law (Field Emission) to Child-Langmuir Law (Space Charge Limited Current) against the 1994 paper (Lau, Liu and Parker, 1994).

## **04** MODELLING SCLC

## WITH COLLISION

Having modelled the transition from field emission to space charge limited current in a vacuum, a model taking into account electron mobility (in solid-state materials for instance), as well as non-typical emission surfaces, can be constructed

## Solid State Materials

$$\sum F = ma \qquad eE - \frac{e}{\mu}V = ma$$

Non Dimensionless Units 
$$ar{J} = rac{1}{2}$$

$$\begin{split} \phi &= \phi_0 \overline{\phi}; \quad J = J_0 \overline{J}; \quad x = x_0 \overline{x}; \quad t = t_0 \overline{t}; \\ \mu &= \mu_0 \overline{\mu}; \quad E = E_0 \overline{E}; \quad v = v_0 \overline{v} \end{split}$$

$$\begin{split} \phi_0 &= \frac{e \epsilon_0^2}{m A^2}; \quad J_0 = A B^2; \quad x_0 = \frac{e \epsilon_0^2}{m A^2 B}; \quad t_0 = \frac{\epsilon_0}{A B}; \\ \mu_0 &= \frac{e \epsilon_0}{m A B}; \quad E_0 = B; \quad v_0 \equiv \frac{x_0}{t_0}, \end{split}$$

$$\begin{split} \overline{v}(\overline{t}) &= \overline{\mu} \Big[ \big( \overline{\mu} \, \overline{J} - \overline{E} \big) \big( e^{-\overline{t}/\overline{\mu}} - 1 \big) + \overline{J} \overline{t} \Big] \\ \overline{x}(\overline{t}) &= \overline{\mu} \Big[ \big( \overline{\mu} \, \overline{J} - \overline{E} \big) \Big( - \overline{\mu} e^{-\overline{t}/\overline{\mu}} - \overline{t} + \overline{\mu} \Big) + \overline{J} \overline{t}^2 / 2 \Big]. \end{split}$$

$$\overline{V} = \frac{\overline{v}(\overline{t})^2}{2} \Big|_0^{\overline{T}} + \int_0^{\overline{T}} d\overline{t} \frac{\overline{v}(\overline{t})^2}{\overline{u}} \qquad \overline{J} = \overline{E}^2 e^{-1/\overline{E}}$$

$$V = \frac{1}{2} \Big|_0 + \int_0^1 dt \frac{1}{\overline{\mu}}$$
  $J = E^2 e^{-1/E}$ 

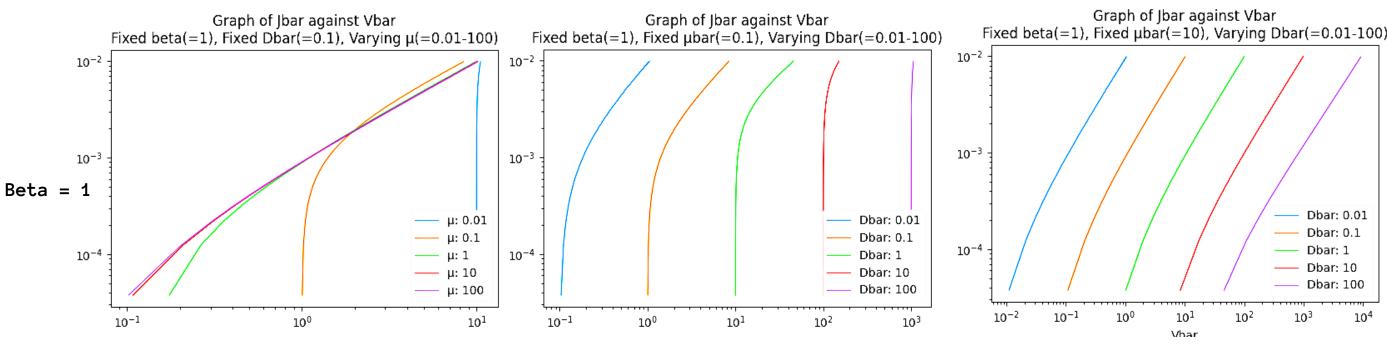
## Numerical Method to Model J against V with varying μ and D:

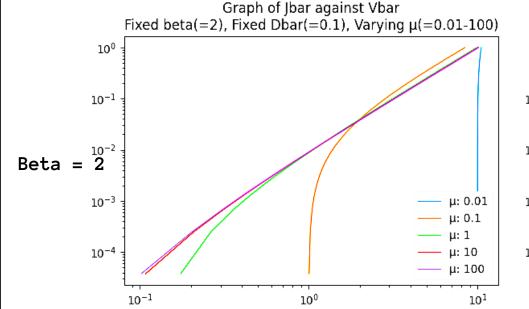
- 1. Define a fixed D.
- 2. Simulate x(t) at a variable E. Keep increasing the time step until x(t) = D. Transit Time  $(t_t)$  is the time taken for the electron to travel length D.
- 3. Find terminal velocity  $v(t_t)$ .
- 4. The voltage, V can then be calculated from  $t_{tr}$  and  $v(t_{tr})$
- 5. Calculate J based on the E chosen in Step 2.
- 6. Record J(E) and V(E)

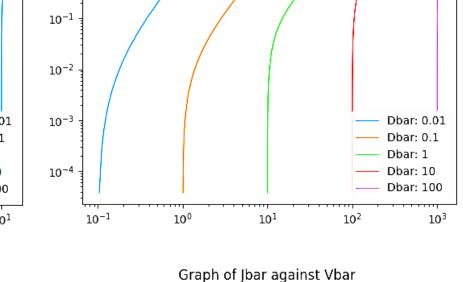
applications

- 7. Repeat 2 to 6 for different E
- 8. Plot J(E) versus V(E) in a log-log plot
- 9. Repeat 1 to 8 for different D. 10. Repeat 1 to 9 for different  $\mu$ .
- 11. Repeat 1 to 10 for different  $\beta$

## **05** RESULTS

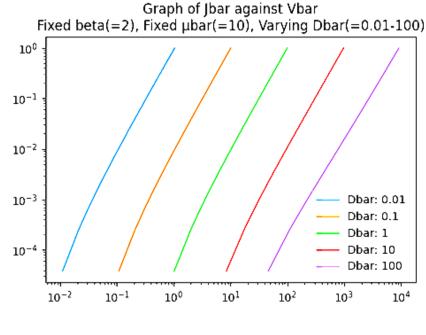


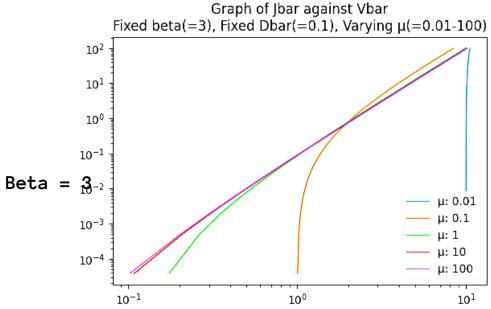


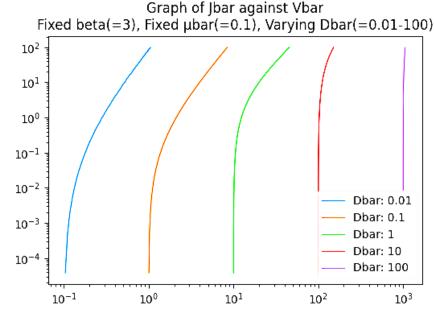


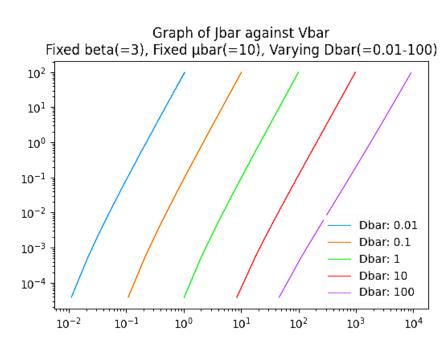
Graph of Ibar against Vbar

Fixed beta(=2), Fixed  $\mu$ bar(=0.1), Varying Dbar(=0.01-100)









## **06** CONCLUSION & FUTURE PLANS

• The modelled transition from field emission to space-charge limited current using FN and Poisson equations at different  $\mu$  and  $\beta$ 

• The result modelled for lower  $\beta$  is more relevant to low-current applications such as EMP-resilient electronics

- The result modelled for higher  $\beta$  is more relevant to high-current applications such as industrial defence
- Models can be plotted onto multidimensional graphs to visualise all variables • Develop a similar model for thermionic emission.

## RELATED LITERATURE

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